

# N-Channel 30 V (D-S) MOSFET

PRODUCT SUMMARY					
V <sub>DS</sub> (V)	$R_{DS(on)}(\Omega)$	I <sub>D</sub> (A)	Q <sub>g</sub> (Typ.)		
30	$0.0035$ at $V_{GS} = 10 \text{ V}$	120 <sup>d</sup>	51.7		
30	$0.0055$ at $V_{GS} = 4.5 \text{ V}$	90 <sup>d</sup>	51.7		

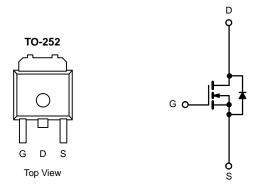
#### **FEATURES**

- Halogen-free According to IEC 61249-2-21 Definition
- TrenchFET® Power MOSFET
- 100 % R<sub>q</sub> and UIS Tested
- Compliant to RoHS Directive 2002/95/EC





- Power Supply
  - Secondary Synchronous Rectification
- DC/DC Converter



N-Channel MOSFET

<b>ABSOLUTE MAXIMUM RATING</b>	$T_C = 25  ^{\circ}C$ , unless other	erwise noted		•	
Parameter	Symbol	Limit	Unit		
Drain-Source Voltage	V <sub>DS</sub>	30			
Gate-Source Voltage	V <sub>GS</sub>	± 20	V		
Continuous Drain Current (T <sub>.1</sub> = 150 °C)	T <sub>C</sub> = 25 °C	1-	120 <sup>d</sup>	A	
Continuous Diairi Current (1) = 130 °C)	T <sub>C</sub> = 70 °C	I <sub>D</sub>	90 <sup>d</sup>		
Pulsed Drain Current		I <sub>DM</sub>	360		
Avalanche Current		I <sub>AS</sub>	40		
Single Avalanche Energy <sup>a</sup>	L = 0.1 mH	E <sub>AS</sub>	380	mJ	
Maniana Banas Birainatia a	T <sub>C</sub> = 25 °C	В	129.5 <sup>b</sup>	W	
Maximum Power Dissipation <sup>a</sup>	T <sub>A</sub> = 25 °C <sup>c</sup>	$ P_D$	50.7		
Operating Junction and Storage Temperature Range		T <sub>J</sub> , T <sub>stg</sub>	- 55 to 175	°C	

THERMAL RESISTANCE RATINGS					
Parameter	Symbol	Limit	Unit		
Junction-to-Ambient (PCB Mount) <sup>c</sup>	R <sub>thJA</sub>	46			
Junction-to-Case (Drain)	R <sub>thJC</sub>	1.21	°C/W		

#### Notes:

- a. Duty cycle  $\leq$  1 %.
- b. See SOA curve for voltage derating.c. When mounted on 1" square PCB (FR-4 material).
- d. Package limited.

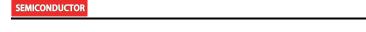


Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit	
Static							
Drain-Source Breakdown Voltage	V <sub>DS</sub>	$V_{DS} = 0 \text{ V}, I_{D} = 250  \mu\text{A}$	30		V		
Gate Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS} = V_{GS}, I_D = 250 \mu A$	1		2.5	V	
Gate-Body Leakage	I <sub>GSS</sub>	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$			± 150	nA	
		V <sub>DS</sub> = 30 V, V <sub>GS</sub> = 0 V			1		
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> = 30 V, V <sub>GS</sub> = 0 V, T <sub>J</sub> = 125 °C			50	μA	
		V <sub>DS</sub> = 30 V, V <sub>GS</sub> = 0 V, T <sub>J</sub> = 150 °C			250		
On-State Drain Current <sup>a</sup>	I <sub>D(on)</sub>	$V_{DS} \ge 10 \text{ V}, V_{GS} = 10 \text{ V}$	50			Α	
Drain Source On State Resistance	В	V <sub>GS</sub> = 10 V, I <sub>D</sub> = 22 A		0.0035	0.0039	Ω	
Drain-Source On-State Resistance <sup>a</sup>	R <sub>DS(on)</sub>	V <sub>GS</sub> = 4.5 V, I <sub>D</sub> = 20 A		0.0055	0.0061		
Forward Transconductance <sup>a</sup>	9 <sub>fs</sub>	V <sub>DS</sub> = 15 V, I <sub>D</sub> = 20 A		110		S	
Dynamic <sup>b</sup>							
Input Capacitance	C <sub>iss</sub>			2780		pF	
Output Capacitance	C <sub>oss</sub>	V <sub>GS</sub> = 0 V, V <sub>DS</sub> = 15 V, f = 1 MHz		641			
Reverse Transfer Capacitance	C <sub>rss</sub>			260			
Total Gate Charge <sup>c</sup>	$Q_g$	V <sub>DS</sub> = 15 V, V <sub>GS</sub> = 10 V, I <sub>D</sub> = 20 A		44	66		
Total Gate Charge				51.7	32.6	nC	
Gate-Source Charge <sup>c</sup>	$Q_{gs}$	$V_{DS} = 15 \text{ V}, V_{GS} = 4.5 \text{ V}, I_{D} = 20 \text{ A}$		7			
Gate-Drain Charge <sup>c</sup>	$Q_{gd}$			6.7			
Gate Resistance	R <sub>g</sub>	f = 1 MHz	0.4	2	4	Ω	
Turn-On Delay Time <sup>c</sup>	t <sub>d(on)</sub>			8	16		
Rise Time <sup>c</sup>	t <sub>r</sub>	$V_{DD} = 15 \text{ V}, R_{L} = 1.5 \Omega$		9	18	ns	
Turn-Off Delay Time <sup>c</sup>	t <sub>d(off)</sub>	$I_D \cong 10 \text{ A}, V_{GEN} = 10 \text{ V}, R_g = 1 \Omega$		35	53		
Fall Time <sup>c</sup>	t <sub>f</sub>			9	18		
Drain-Source Body Diode Ratings a	nd Characteris	stics T <sub>C</sub> = 25 °C <sup>b</sup>	•	•			
Continuous Current	I <sub>S</sub>				120	^	
Pulsed Current	I <sub>SM</sub>				360	A	
Forward Voltage <sup>a</sup>	$V_{SD}$	I <sub>F</sub> = 10 A, V <sub>GS</sub> = 0 V		0.75	1.5	V	
Reverse Recovery Time	t <sub>rr</sub>			34	51	ns	
Peak Reverse Recovery Current	I <sub>RM(REC)</sub>	$I_F = 10 \text{ A}, dI/dt = 100 \text{ A}/\mu\text{s}$		2	3	Α	
Reverse Recovery Charge	Q <sub>rr</sub>			34	51	nC	

#### Notes:

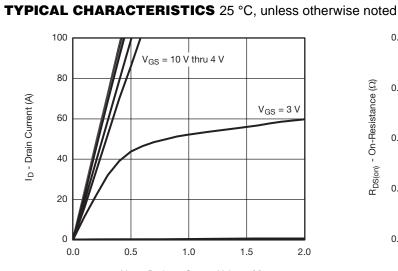
- a. Pulse test; pulse width  $\leq$  300 µs, duty cycle  $\leq$  2 %.
- b. Guaranteed by design, not subject to production testing.
- c. Independent of operating temperature.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

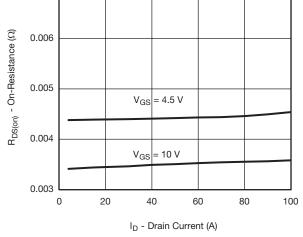


**Din-Tek** 

## www.din-tek.jp

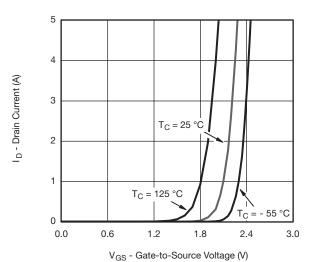


V<sub>DS</sub> - Drain-to-Source Voltage (V) Drain to Source Voltage vs. ID

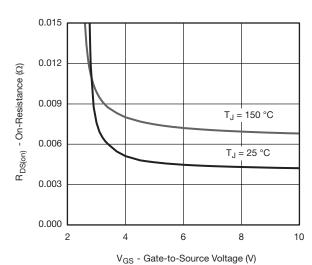


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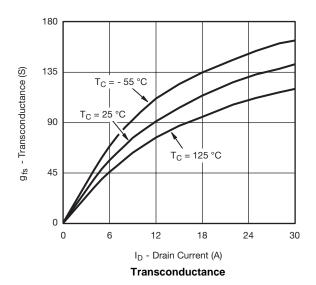
On-Resistance vs. Drain Current

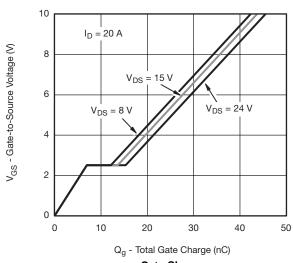


**Transfer Characteristics** 



On-Resistance vs. Gate-to-Source Voltage

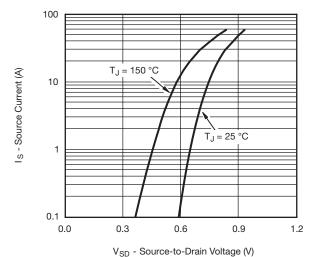




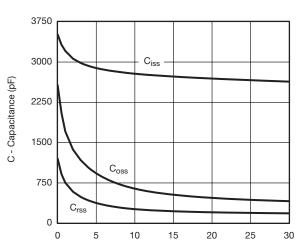
**Gate Charge** 



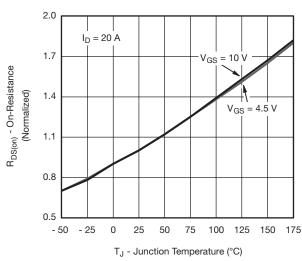
#### TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



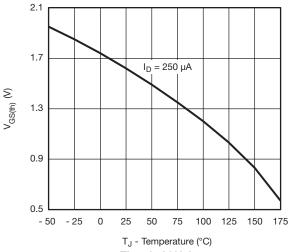
Source-Drain Diode Forward Voltage



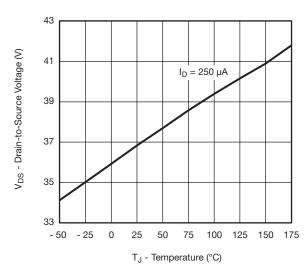
 $V_{DS}$  - Drain-to-Source Voltage (V)  $\label{eq:capacitance}$ 



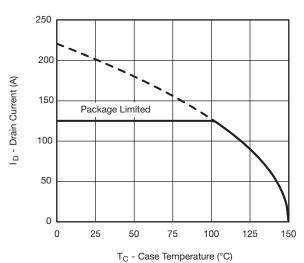
On-Resistance vs. Junction Temperature



Threshold Voltage

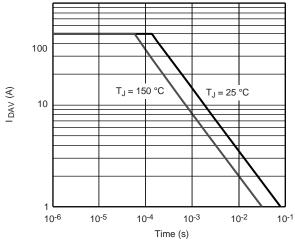


Drain Source Breakdown vs. Junction Temperature

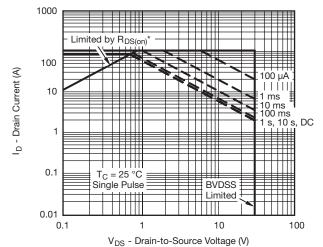


**Current Derating** 

#### TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted

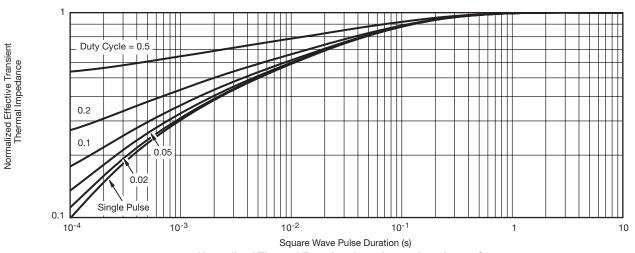


Single Pulse Avalanche Current Capability vs. Time



 $^{\star}$  V  $_{GS}$  > minimum V  $_{GS}$  at which R  $_{DS(on)}$  is specified



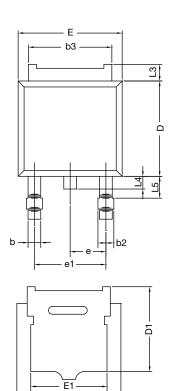


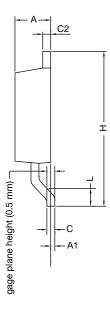
Normalized Thermal Transient Impedance, Junction-to-Case





# **TO-252AA CASE OUTLINE**



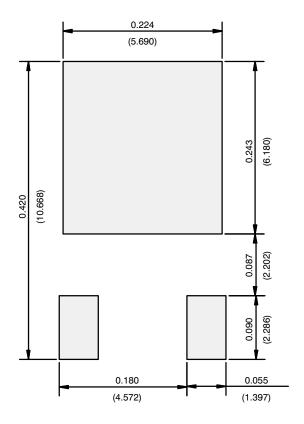


	MILLIN	METERS	RS INCHES			
DIM.	MIN.	MAX.	MIN.	MAX.		
Α	2.18	2.38	0.086	0.094		
A1	-	0.127	-	0.005		
b	0.64	0.88	0.025	0.035		
b2	0.76	1.14	0.030	0.045		
b3	4.95	5.46	0.195	0.215		
С	0.46	0.61	0.018	0.024		
C2	0.46	0.89	0.018	0.035		
D	5.97	6.22	0.235	0.245		
D1	5.21	-	0.205	-		
Е	6.35	6.73	0.250	0.265		
E1	4.32	-	0.170	-		
Н	9.40	10.41	0.370	0.410		
е	2.28 BSC		0.090 BSC			
e1	4.56	BSC 0.180 BSC		4.56 BSC		BSC
L	1.40	1.78	0.055	0.070		
L3	0.89	1.27	0.035	0.050		
L4	-	1.02	-	0.040		
L5	1.14	1.52	0.045	0.060		
ECN: X12-0247-Rev. M, 24-Dec-12						

#### DWG: 5347 Note

• Dimension L3 is for reference only.

### **RECOMMENDED MINIMUM PADS FOR DPAK (TO-252)**



Recommended Minimum Pads Dimensions in Inches/(mm)

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